

16V, 500mA, Low Quiescent Current Linear Regulator

DESCRIPTION

The MP2018 is a low-power linear regulator that supplies power to systems with high-voltage batteries. The MP2018 includes a wide 3V to 16V input voltage range, low dropout voltage, and low quiescent supply current. The low quiescent current and low dropout voltage allow the MP2018 to operate at extremely low power levels. Therefore, the MP2018 is ideal for low-power microcontrollers and battery-powered equipment.

The MP2018 provides two fixed output voltage options: 3.3V and 5.0V.

The regulator output current is limited internally, and the device is protected against short-circuit, overload, and over-temperature conditions. The MP2018 also includes thermal shutdown and current-limiting fault protection.

The MP2018 is available in a TO252-5 package.

FEATURES

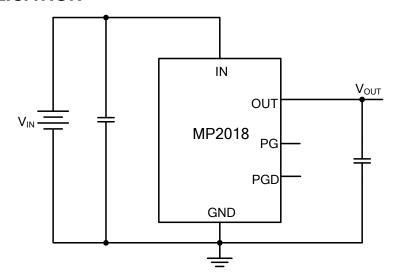
- 3V to 16V Input Range
- 10µA Quiescent Supply Current
- Stable with Low-Value Output Ceramic Capacitor (>0.47µF)
- 500mA Specified Current
- Fixed Output Voltage
- Output ±2% Accuracy
- Specified Current Limit
- Power Good
- Programmable Power Good Delay
- Thermal Shutdown and Short-Circuit Protection (SCP)
- -40°C to +150°C Specified Junction Temperature Range
- Available in a TO252-5 Package

APPLICATIONS

- Portable/Battery-Powered Equipment
- Ultra-Low Power Microcontrollers
- Cellular Handsets
- Medical Imaging

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TYPICAL APPLICATION





ORDERING INFORMATION

Part Number*	Package	Top Marking
MP2018GZD-33	TO252-5	See Below
MP2018GZD-5	TO252-5	See Below

^{*} For Tape & Reel, add suffix -Z (e.g.: MP2018GZD-5-Z).

TOP MARKING (MP2018GZD-33)

MPS YYWW MP2018-33 LLLLLLLL

MPS: MPS prefix YY: Year code WW: Week code

MP2018-33: Part number LLLLLLLL: Lot number

TOP MARKING (MP2018GZD-5)

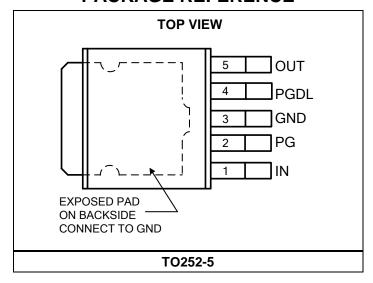
MPS YYWW MP2018-5 LLLLLLLL

MPS: MPS prefix YY: Year code WW: Week code

MP2018-5: Part number LLLLLLLL: Lot number



PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS (1)
IN0.3V to +20V
OUT0.3V to +17V
PG0.3V to +15V
PGDL0.3V to +6V
Lead temperature260°C
Storage temperature65°C to +150°C
Continuous power dissipation $(T_A = +25^{\circ}C)^{(2)}$
TO252-52.27W
10252-52.27 W
ESD Susceptibility (3)
ESD Susceptibility (3) Human body mode (HBM)4kV
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ESD Susceptibility (3) Human body mode (HBM)4kV
ESD Susceptibility (3) Human body mode (HBM)

 $T_A \le T_J \le +150$ °C

Thermal Resistance (5)	$oldsymbol{ heta}_{JA}$	$oldsymbol{ heta}$ JC	
TO252-5	. 55	3	.°C/W

NOTES:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-to-ambient thermal resistance θ_{JA} , and the ambient temperature T_A . The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX)- T_A)/ θ_{JA} . Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- Devices are ESD-sensitive. Handling precaution is recommended.
- The device is not guaranteed to function outside of its operating conditions.
- 5) Measured on JESD51-7, 4-layer PCB.



ELECTRICAL CHARACTERISTICS

 V_{IN} = 13.5V, T_J = +25°C, unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units	
		0 < Iouт < 1mA		12	17		
GND pin current	I_{GND}	1mA < I _{OUT} < 30mA		16	22	μA	
		30mA < Iоит < 500mA		105	150		
Load current limit	ILIMIT	V _{OUT} = 0V	550	900	1450	mA	
Output voltage accuracy		MP2018GZD-5, $V_{IN} = 6V$ to 16V, $I_{LOAD} = 5mA$	4.9	5	5.1	V	
Output Voltage accuracy		MP2018GZD-33, $V_{IN} = 4.3V$ to 16V, $I_{LOAD} = 5mA$	3.234	3.3	3.366	v	
		MP2018GZD-5, I _{LOAD} = 300mA, V _{DROPOUT} = V _{IN} - V _O		400	650		
Dropout voltage (6)	Vdropout	MP2018GZD-33, I _{LOAD} = 300mA, V _{DROPOUT} = V _{IN} - V _O		500	700	mV	
		MP2018GZD-5, I _{LOAD} = 500mA, V _{DROPOUT} = V _{IN} - V _O		750	1000		
		MP2018GZD-33, $I_{LOAD} = 500$ mA, $V_{DROPOUT} = V_{IN} - V_{O}$		1000	1300		
Line regulation		$V_{IN} = 8V$ to 16V, $I_{LOAD} = 5mA$	-10	1	10	mV	
Load regulation		I _{LOAD} = 5mA to 500mA		1	15	mV	
		100Hz, C _{OUT} = 10μF, I _{LOAD} = 10mA		57		dB	
Output voltage PSRR (7)		1kHz, C _{OUT} = 10µF, I _{LOAD} = 10mA		45		dB	
		100kHz, C _{OUT} = 10μF, I _{LOAD} = 10mA		51		dB	
Startup recognize time		MP2018GZD-5, $I_{LOAD} = 10$ mA, $C_{OUT} = 22\mu F$		1	2	mo	
Startup response time		MP2018GZD-33, $I_{LOAD} = 10$ mA, $C_{OUT} = 22\mu F$		0.6	1.5	— ms	
PG rising threshold			90%	93%	96%	Vouт	
PG rising threshold hysteresis				5%		V _{OUT}	
PG low voltage		Sink 1mA current		0.1	0.4	V	
PG leakage current		$V_{PG} = 5V$			1	μA	
PGDL charging current	I_{PGDL}	$V_{PGDL} = 1V$	3	5.5	9	μΑ	
PGDL rising threshold			1.5	1.65	2	V	
PGDL falling threshold			0.2	0.4	0.7	V	
PG delay time	tpgdl	C _{PGDL} = 47nF, 10% to 90% PGDL rising threshold	6	11	14	ms	
PG reaction time		C _{PGDL} = 47nF		0.5	2	μs	
Thermal shutdown (7)	T _{SD}			165		°C	
Thermal shutdown hysteresis (7)	ΔTSD			30		°C	

NOTES

⁶⁾ Dropout voltage: Measured when the output voltage (V_{OUT}) has dropped 100mV from the nominal value obtained at V_{IN} = 13.5V.

¹⁾ Derived from bench characterization. Not tested in production.



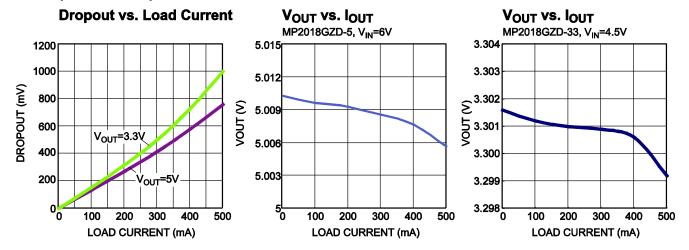
PIN FUNCTIONS

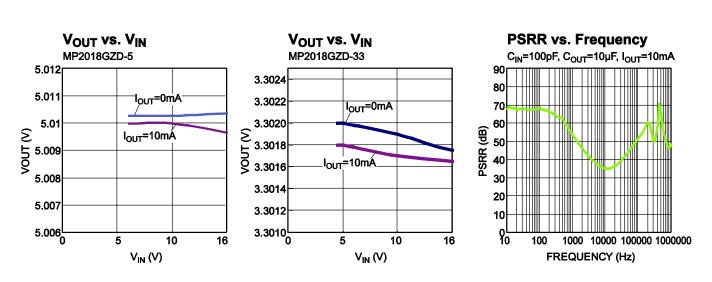
Pin #	Name	Description
1	IN	Input voltage. Connect a 3V to 16V supply to IN.
2	PG	Power good.
3	GND	Ground. GND is connected to the exposed pad internally. GND and the exposed pad must be connected to the same ground plane.
4	PGDL	Programmable power good delay time.
5	OUT	Regulated output voltage. Connect a low-value ceramic capacitor (≥0.47µF) to the output for stability.



TYPICAL PERFORMANCE CHARACTERISTICS

 $C_{IN} = 1 \mu F$, $C_{OUT} = 22 \mu F$, $V_{OUT} = 5 V$, $T_A = 25 ^{\circ} C$, unless otherwise noted.

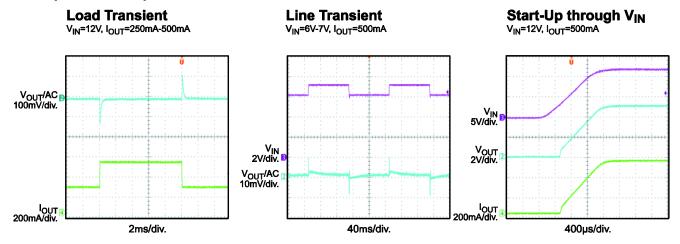




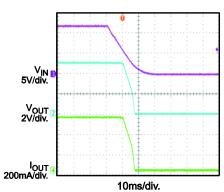


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

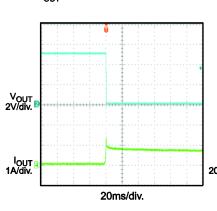
 $C_{IN} = 1\mu F$, $C_{OUT} = 22\mu F$, $V_{OUT} = 5V$, $T_A = 25^{\circ}C$, unless otherwise noted.



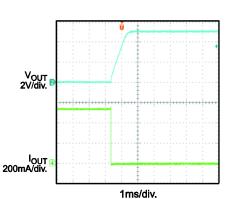
Shutdown through V_{IN} V_{IN}=12V, I_{OUT}=500mA



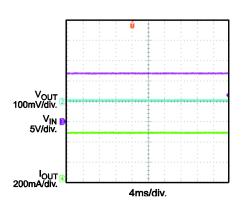
Short-Circuit Entry I_{OUT}=0mA to Short Circuit



Short-Circuit Recovery Short Circuit to I_{OUT}=0mA



Short-Circuit Steady State VIN=12V





BLOCK DIAGRAM

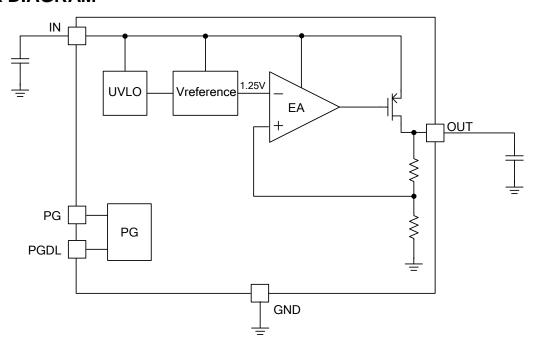


Figure 1: Functional Block Diagram



OPERATION

The MP2018 is a linear regulator that supplies power to systems with high-voltage batteries. The MP2018 includes a wide 3V to 16V input range, low dropout voltage, and low quiescent supply current.

Short-Circuit Protection (SCP)

The regulator output current is limited internally, and the device is protected against short-circuit and overload conditions. The peak output current is limited to around 900mA, which exceeds the 500mA recommended continuous output current.

Thermal Shutdown

When the junction temperature exceeds the upper threshold (165°C), the thermal sensor sends a signal to the control logic to shut down the IC. The IC restarts when the temperature has cooled sufficiently (135°C).

The maximum power output current is a function of the package's maximum power dissipation for a given temperature.

The maximum power dissipation depends on the thermal resistance of the case and the circuit board, the temperature difference between the die junction and the ambient air, and the rate of the air flow. GND and the exposed pad must be connected to the ground plane for proper dissipation.

Power Good (PG) Output

The MP2018 has a power good pin (PG). PG is the open drain of an internal MOSFET and should be connected to the output voltage (V_{OUT}) or an external voltage source (<15V) through a resistor (i.e.: $100k\Omega$). If V_{OUT} reaches 93% of the nominal value, the MOSFET turns off, and PG is pulled high by V_{OUT} or an external voltage source. When V_{OUT} drops to 88% of the nominal value, the PG voltage is pulled to GND.

There is a delay time when PG asserts high. The delay time can be programmed by adding a capacitor on PGDL. Select a capacitor for PGDL using Equation (1):

$$C_{PGDL}(nF) = \frac{t_{PGDL}(ms) \times I_{PGDL}(\mu A)}{V_{th_PGDL}(V)}$$
(1)

Where t_{PGDL} is the desired delay time when PG asserts high, I_{PGDL} is the PGDL charging current, and V_{th} PGDL is 1.65V.

Figure 2 shows the power good timing.

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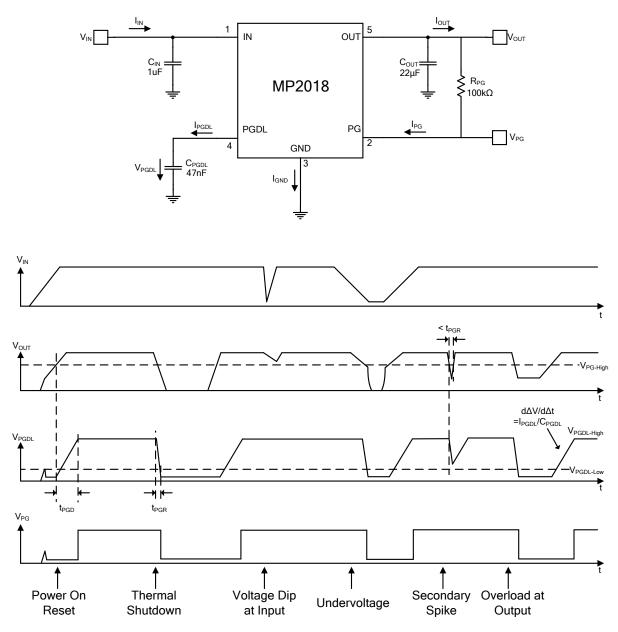


Figure 2: Power Good Timing



APPLICATION INFORMATION

Selecting the Input Capacitor

For proper operation, place a dielectric type X5R or X7R ceramic capacitor between 1 - $10\mu F$ (C1) between the input pin and ground. Larger values in this range help improve line transient response.

Selecting the Output Capacitor

For stable operation, use a dielectric type X5R or X7R ceramic capacitor (C2) between 1 - $22\mu F$. Larger values in this range help improve load transient response and reduce noise. Output capacitors of other dielectric types may be used but are not recommended since their capacitance can deviate greatly from their rated value over temperature.

PCB Layout Guidelines

Efficient PCB layout is critical for good regulation, ripple rejection, transient response, and thermal performance. It is highly recommended to duplicate the EVB layout for optimal performance. For best results, refer to Figure 3, Figure 4, and follow the guidelines below.

- Place the input and output bypass ceramic capacitors close to IN and OUT respectively.
- Connect IN, OUT, and especially GND to a large copper area to cool the chip and improve thermal performance and longterm reliability.

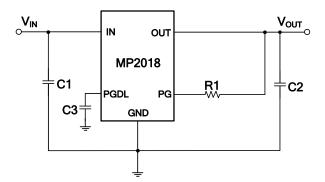
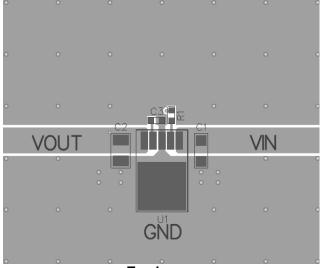
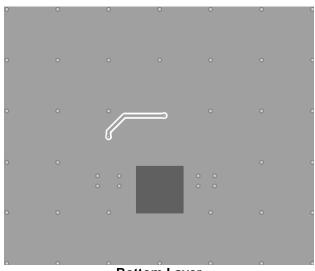


Figure 3: MP2018 Schematic



Top Layer



Bottom Layer Figure 4: Recommended Layout

Design Example

Figure 5 shows a design example following the application guidelines.

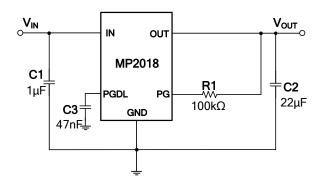


Figure 5: Design Example



TYPICAL APPLICATION CIRCUIT

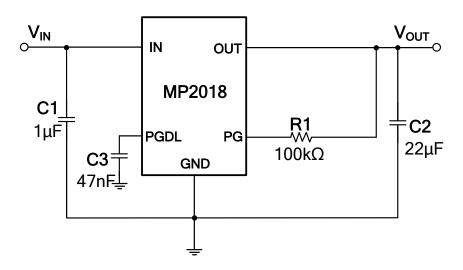
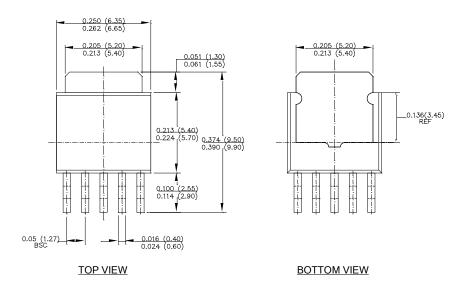


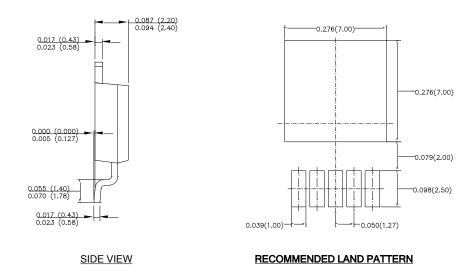
Figure 6: Typical Application Circuit



PACKAGE INFORMATION

TO252-5





NOTE:

- 1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4) DRAWING CONFORMS TO JEDEC TO-252.
- 5) DRAWING IS NOT TO SCALE.

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